



ADS7800

www.burr-brown.com/databook/ADS7800.html

12-Bit 3µs Sampling ANALOG-TO-DIGITAL CONVERTER

FEATURES

- 333k SAMPLES PER SECOND
- STANDARD ±10V AND ±5V INPUT RANGES
- DC PERFORMANCE OVER TEMP: No Missing Codes
 1/2LSB Integral Linearity Error
 3/4LSB Differential Linearity Error
- AC PERFORMANCE OVER TEMP:
 72dB Signal-to-Noise Ratio
 80dB Spurious-free Dynamic Range
 80dB Total Harmonic Distortion
- INTERNAL SAMPLE/HOLD, REFERENCE, CLOCK, AND 3-STATE OUTPUTS
- POWER DISSIPATION: 215mW max
- PACKAGE: 24-Pin Single-wide DIP 24-Lead SOIC

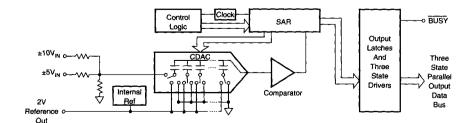
DESCRIPTION

The ADS7800 is a complete 12-bit sampling analog-to-digital converter using state-of-the-art CMOS structures. It contains a complete 12-bit successive approximation A/D converter with internal sample/hold, reference, clock, digital interface for microprocessor control, and three-state output drivers.

The ADS7800 is specified at a 333kHz sampling rate. Conversion time is factory set for 2.70µs max over temperature, and the high speed sampling input stage insures a total acquisition and conversion time of 3µs max over temperature. Precision, laser-trimmed scaling resistors provide industry-standard input ranges of ±5V or ±10V.

AC and DC performance are completely specified. Two grades based on linearity and dynamic performance are available to provide the optimum price/performance fit in a wide range of applications.

The 24-pin ADS7800 is available in plastic and sidebraze hermetic 0.3" wide DIPs, and in an SOIC package. It operates from a +5V supply and either a -12V or -15V supply. The ADS7800 is available in grades specified over 0°C to +70°C and -40°C to +85°C temperature ranges.



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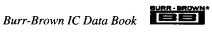
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SPECIFICATIONS

ELECTRICAL

At $T_A = T_{MIN}$ to T_{MAX} , Sampling Frequency, $f_{S_1} = 333kHz$, $-V_S = -15V$, $V_S = +5V$, unless otherwise specified.

	CONDITIONS	ADS7800JP/JU/AH			ADS7800KP/KU/BH			i
PARAMETER		MIN TYP		MAX	MIN	TYP	MAX	UNITS
RESOLUTION				12			*	Bits
ANALOG INPUT								
Voltage Ranges			±10V/±5V					٧
Impedance	±10V Range	4.4	6.3	8.1	l :	1 : [kΩ
	±5V Range	2.9	4.2	5.4	*	<u> </u>	*	kΩ
THROUGHPUT SPEED								
Conversion Time	Conversion Alone Acquisition + Conversion		2.5 2.6	2.7 3.0		1 : 1	•	μs
Complete Cycle Throughput Rate	Acquisition + Conversion	333	380	3.0	١.			μs kHz
			- 360		 			KOZ
DC ACCURACY Full Scale Error ⁽¹⁾				±0.50		1	±0.35	%
Full Scale Error Drift			6	10.50		1 . 1	10.55	ppm/°(
Integral Linearity Error			1 1	±1	1	i	±1/2	LSB(2
Differential Linearity Error	ł l			±1			±3/4	LSB
No Missing Codes]		Guaranteed			Guaranteed		
Bipolar Zero(1)				±4	1		±2	LSB
Bipolar Zero Drift			1			•		ppm/°(
Power Supply Sensitivity	[[
	-16.5V < -V _S < -13.5V			±1/2	ľ		•	LSB
	-12.6V < -V _S < -11.4V			±1/2		l i		LSB
Transition Noise(3)	+4.75V < V _S < +5.25V		0.1	±1		.	±1/2	LSB LSB
AC ACCURACY			• • • •			1		
Spurious-Free Dynamic Range	f _{IN} = 47kHz	74	77		77	80		dB ⁽⁴⁾
Total Harmonic Distortion	f _{IN} = 47kHz	' '	-77	-74	l ''	-80	-77	dB
Two-tone Intermodulation Distortion	f _{IN1} = 24.4kHz (-6dB)		-77	-74		-80	-77	dB
	f _{IN2} = 28.5kHz (-6dB)					"		
Signal-to-(Noise + Distortion) Ratio	f _{IN} = 47kHz	67	70		69	72		dB
Signal-to-Noise Ratio (SNR)	f _{IN} = 47kHz	68	71		70	73		dB
SAMPLING DYNAMICS								
Aperture Delay			13			•		ns
Aperture Jitter			150			'		ps, rm
Transient Response(5)			130 150			:		ns
Overvoltage Recovery ⁽⁶⁾			150			-		ns
INTERNAL REFERENCE VOLTAGE Voltage		1.9	2.0	2.1		1 . 1		v
Source Current Available		1.5	10	2.1				μA
for External Loads			"			1		μπ
DIGITAL INPUTS						+		
Logic Levels						1 1		
V _{IL}		-0.3		+0.8		1	•	Ιv
V _{iH}		+2.4		+5.3		1	•	V
{ _{IL}		-5				1 1		μА
I _{IH}		+5			•	1 1		μΑ
DIGITAL OUTPUTS								
Data Format			F	arallel, 12-bi		it		
Data Coding	, ,,,,	0.0		Binary Off	set Binary			l
V _{OL}	I _{SINK} = 1.6mA	0.0		+0.4	:			V V
V _{OH} I _{LEAKAGE} (High-Z State)	I _{SOURCE} = 500μA	+2.4	±0.1	+5.0 ±5		.	*	ν μA
POWER SUPPLIES			10.1					<u>μη</u>
Rated Voltage					1			
-Vs		-11.4	-15	-16.5		•	•	v
V _S (V _{SA} and V _{SD})		+4.75	+5.0	+5.25		•	•	v
Current								
-I _S			3.5	6		•	•	mA
Is			18	25		•	*	mA
Power Consumption	1		135	215	l	ı •	•	mW



Or, Call Customer Service at 1-800-548-6132 (USA Only)

SPECIFICATIONS (CONT)

ELECTRICAL

At $T_A = T_{MIN}$ to T_{MAX} , Sampling Frequency, $f_S = 333kHz$, $-V_S = -15V$, $V_S = +5V$, unless otherwise specified

	7	ADS	ADS7800JP/JU/AH			ADS7800KP/KU/BH		
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
TEMPERATURE RANGE								Γ
Specification	JP/JU/KP/KU	0	Ì	+70	٠ ١)		°C
1	AH/BH	-40	ĺ	+85	i *	1	•	°C
Operating	JP/KP/JU/KU	-40	l	+85	٠		*	∘c
Storage		-65	}	+150	•			°C

^{*} Same as specification for ADS7800JP/JU/AH.

NOTES: (1) Adjustable to zero with external potentiometer. (2) LSB means Least Significant Bit. For ADS7800, 1LSB = 2.44mV for the ±5V range, 1LSB = 4.88mV for the ±10V range. (3) Noise was characterized over temperature near full scale, 0V, and negative full scale. 0.1LSB represents a typical rms level of noise at the worst case, which was near full scale input at +125°C. (4) All specifications in dB are referred to a full-scale input, either ±10V or ±5V. (5) For full scale step input, 12-bit accuracy attained in specified time. (6) Recovers to specified performance in specified time after 2 x F₈ input overvoltage.



ABSOLUTE MAXIMUM RATINGS

-V _S to ANALOG COMMON	16.5V
Vs to DIGITAL COMMON	
Pin 23 (V _{SD}) to Pin 24 (V _{SA})	
ANALOG COMMON to DIGITAL COMMON	±1V
Control Inputs to DIGITAL COMMON	0.3 to V _S + 0.3V
Analog Input Voltage	±20V
Maximum Junction Temperature	160°C
Internal Power Dissipation	750mW
Lead Temperature (soldering, 10s)	+300°C
Thermal Resistance, θ _{JA} :	
Plastic DIP	100°C/W
SOIC	100°C/W
Ceramic	50°C/W

ELECTROSTATIC DISCHARGE SENSITIVITY

The ADS7800 is an ESD (electrostatic discharge) sensitive device. The digital control inputs have a special FET structure, which turns on when the input exceeds the supply by 18V, to minimize ESD damage. However, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. When not in use, devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.

PACKAGE/ORDERING INFORMATION

PRODUCT	INTEGRAL LINEARITY ERROR (LSB)	SIGNAL-TO- (NOISE+DISTORTION) RATIO (dB min)	SPECIFICATION TEMPERATURE RANGE (°C)	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾
ADS7800JP	±1	67	0 to +70	24-Pin Plastic DIP	243
ADS7800KP	±1/2	69	0 to +70	24-Pin Plastic DIP	243
ADS7800JU	±1	67	0 to +70	24-Pin Plastic SOIC	239
ADS7800KU	±1/2	69	0 to +70	24-Pin Plastic SOIC	239
ADS7800AH	±1	67	-40 to +85	24-Pin Ceramic DIP	245
ADS7800BH	±1/2	69	-40 to +85	24-Pin Ceramic DIP	245

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

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PIN ASSIGNMENTS

PIN#	NAME	DESCRIPTION
1	IN1	±10V Analog Input. Connected to GND for ±5V range.
2	IN2	±5V Analog Input. Connected to GND for ±10V range.
3	REF	+2V Reference Output. Bypass to GND with 22μF to 47μF Tantalum. Buffer for external loads.
4	AGND	Analog Ground. Connect to pin 13.
5	D11	Data Bit 11. Most Significant Bit (MSB).
6	D10	Data Bit 10.
7	D9	Data Bit 9.
8	D8	Data Bit 8.
9	D7	Data Bit 7 if HBE is LOW; LOW if HBE is HIGH.
10	D6	Data Bit 6 if HBE is LOW; LOW if HBE is HIGH.
11	D5	Data Bit 5 if HBE is LOW; LOW if HBE is HIGH.
12	D4	Data Bit 4 if HBE is LOW; LOW if HBE is HIGH.
13	DGND	Digital Ground. Connect to pin 4.
14	D3	Data Bit 3 if HBE is LOW; Data Bit 11 if HBE is HIGH.
15	D2	Data Bit 2 if HBE is LOW; Data Bit 10 if HBE is HIGH.
16	D1	Data Bit 1 if HBE is LOW; Data Bit 9 if HBE is HIGH.
17	D0	Data Bit 0 if HBE is LOW. Least Significant Bit (LSB); Data Bit 8 if HBE is HIGH.
18	HBE	High Byte Enable. When held LOW, data output as 12- bits in parallel. When held HIGH, four MSBs presented on pins 14-17, pins 9-12 output LOWs. Must be LOW to intitate conversion.
19	₽√Ĉ	Read/Convert. Falling edge initiates conversion when CS is LOW, HBE is LOW, and BUSY is HIGH.
20	ĊS	Chip Select. Outputs in Hi-Z state when HIGH. Must be LOW to initiate conversion or read data.
21	BUSY	Busy. Output LOW during conversion. Data valid on rising edge in Convert Mode.
22	-V _s	Negative Power Supply12V or -15V. Bypass to GND.
23	V _{SD}	Positive Digital Power Supply. +5V. Connect to pin 24, and bypass to GND.
24	V _{SA}	Positive Analog Power Supply. +5V. Connect to pin 23, and bypass to GND.

PIN CONFIGURATION

